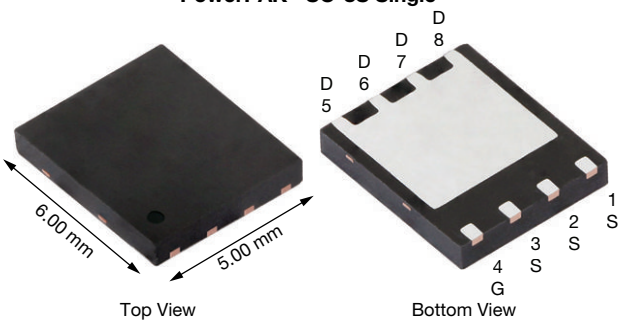
N-Channel 60 V (D-S) MOSFET

PowerPAK® SO-8S Single



Top View | Bottom View

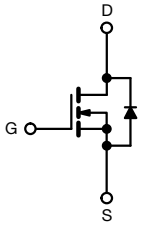
FEATURES

- TrenchFET® Gen IV power MOSFET
- Very low R_{DS} x Q_g figure-of-merit (FOM)
- Leadership $R_{DS(on)}$ minimizes power loss from conduction
- 100 % R_g and UIS tested
- Enhance power dissipation and lower R_{thJC}
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT
HALOGEN FREE

APPLICATIONS

- Synchronous rectification
- DC/DC converters
- OR-ing and hot swap switch
- Power supplies
- Motor drive control
- Battery management



N-Channel MOSFET

PRODUCT SUMMARY	
V_{DS} (V)	60
$R_{DS(on)}$ max. (Ω) at V_{GS} = 10 V	0.00115
$R_{DS(on)}$ max. (Ω) at V_{GS} = 7.5 V	0.0013
Q_g typ. (nC)	81
I_D (A) [a]	359
Configuration	Single

ORDERING INFORMATION	
Package	PowerPAK SO-8S
Lead (Pb)-free and halogen-free	SiRS4600DP-T1-RE3

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V_{DS}	60	V
Gate-source voltage		V_{GS}	± 20	
Continuous drain current (T_J = 150 °C)	T_C = 25 °C	I_D	359	A
	T_C = 70 °C		287	
	T_A = 25 °C		62 [b, c]	
	T_A = 70 °C		50 [b, c]	
Pulsed drain current (t = 100 µs)		I_{DM}	500	
Continuous source-drain diode current	T_C = 25 °C	I_S	252	
	T_A = 25 °C		7.5 [b, c]	
Single pulse avalanche current	L = 0.1 mH	I_{AS}	68	
Single pulse avalanche energy		E_{AS}	231	mJ
Maximum power dissipation	T_C = 25 °C	P_D	278	W
	T_C = 70 °C		178	
	T_A = 25 °C		8.3 [b, c]	
	T_A = 70 °C		5.3 [b, c]	
Operating junction and storage temperature range		T_J, T_{stg}	-55 to +150	°C
Soldering recommendations (peak temperature) [c]			260	

THERMAL RESISTANCE RATINGS

PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction-to-ambient [b]	t ≤ 10 s	R_{thJA}	10	15	°C/W
Maximum junction-to-case (drain)	Steady state	R_{thJC}	0.3	0.45	

Notes

a. T_C = 25 °C
b. Surface mounted on 1" x 1" FR4 board
c. t = 10 s
d. See solder profile (www.vishay.com/doc?73257). The PowerPAK SO-8S is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components
f. Maximum under steady state conditions is 45 °C/W

For technical questions, contact: pmostechsupport@vishay.com

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SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)						
PARAMETER	**SYMBOL**	**TEST CONDITIONS**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static						
Drain-source breakdown voltage	V_{DS}	V_{GS} = 0 V, I_D = 250 µA	60	-	-	V
V_{DS} temperature coefficient	$\Delta V_{DS}/T_J$	I_D = 10 mA	-	32	-	mV/°C
$V_{GS(th)}$ temperature coefficient	$\Delta V_{GS(th)}/T_J$	I_D = 250 µA	-	-8.1	-	
Gate-source threshold voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA	2	-	4	V
Gate-source leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V	-	-	± 100	nA
Zero gate voltage drain current	I_{DSS}	V_{DS} = 60 V, V_{GS} = 0 V	-	-	1	µA
		V_{DS} = 60 V, V_{GS} = 0 V, T_J = 55 °C	-	-	10	
Drain-source on-state resistance [a]	$R_{DS(on)}$	V_{GS} = 10 V, I_D = 20 A	-	0.00091	0.00115	Ω
		V_{GS} = 7.5 V, I_D = 20 A	-	0.00103	0.0013	
Forward transconductance [a]	g_{fs}	V_{DS} = 15 V, I_D = 45 A	-	140	-	S
Dynamic [b]						
Input capacitance	C_{iss}	V_{DS} = 30 V, V_{GS} = 0 V, f = 1 MHz	-	7655	-	pF
Output capacitance	C_{oss}		-	1775	-	
Reverse transfer capacitance	C_{rss}		-	57	-	
Total gate charge	Q_g	V_{DS} = 30 V, V_{GS} = 10 V, I_D = 20 A	-	108	162	nC
		V_{DS} = 30 V, V_{GS} = 7.5 V, I_D = 20 A	-	81	122	
Gate-source charge	Q_{gs}		-	33	-	
Gate-drain charge	Q_{gd}		-	14	-	
Output charge	Q_{oss}	V_{DS} = 30 V, V_{GS} = 0 V	-	111	-	
Gate resistance	R_g	f = 1 MHz	0.24	1.2	2.4	Ω
Turn-on delay time	$t_{d(on)}$	V_{DD} = 30 V, R_L = 3 Ω, $I_D \cong$ 10 A, V_{GEN} = 10 V, R_g = 1 Ω	-	21	40	ns
Rise time	t_r		-	13	25	
Turn-off delay time	$t_{d(off)}$		-	45	90	
Fall time	t_f		-	10	20	
Turn-on delay time	$t_{d(on)}$	V_{DD} = 30 V, R_L = 3 Ω, $I_D \cong$ 10 A, V_{GEN} = 7.5 V, R_g = 1 Ω	-	25	50	
Rise time	t_r		-	23	50	
Turn-off delay time	$t_{d(off)}$		-	40	80	
Fall time	t_f		-	10	20	
Drain-Source Body Diode Characteristics						
Continuous source-drain diode current	I_S	T_C = 25 °C	-	-	218	A
Pulse diode forward current	I_{SM}		-	-	500	
Body diode voltage	V_{SD}	I_S = 10 A, V_{GS} = 0 V	-	0.70	1.1	V
Body diode reverse recovery time	t_{rr}	I_F = 10 A, di/dt = 100 A/µs, T_J = 25 °C	-	70	140	ns
Body diode reverse recovery charge	Q_{rr}		-	132	260	nC
Reverse recovery fall time	t_a		-	42	-	ns
Reverse recovery rise time	t_b		-	28	-	

Notes

a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %

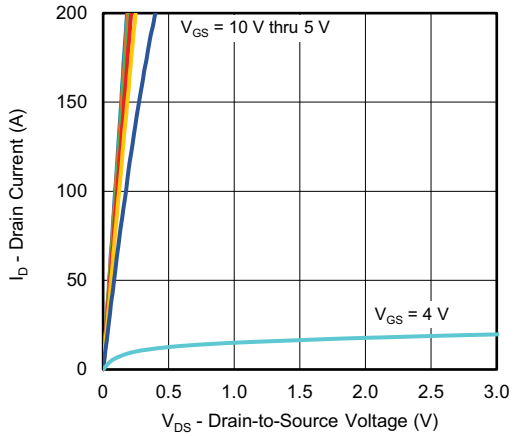
b. Guaranteed by design, not subject to production testing

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

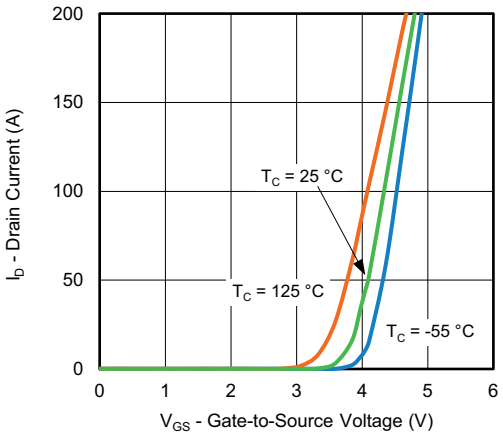
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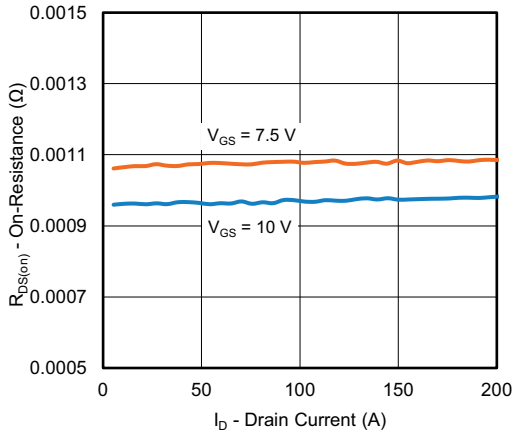
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



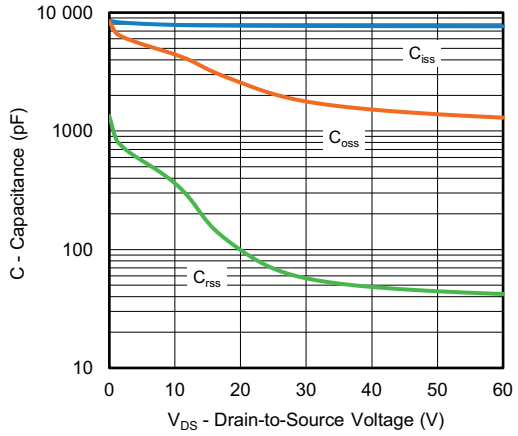
Output Characteristics



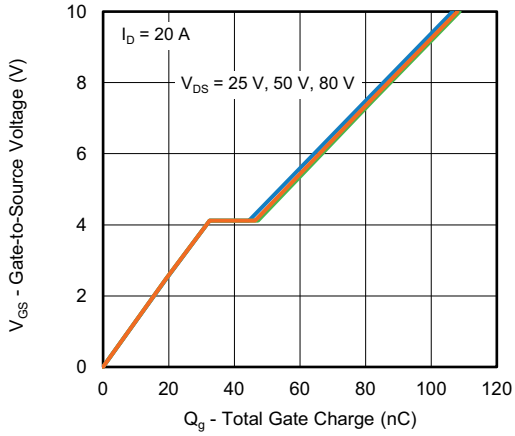
Transfer Characteristics



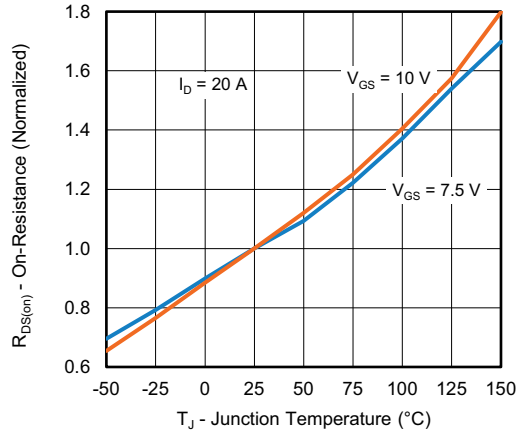
On-Resistance vs. Drain Current and Gate Voltage



Capacitance



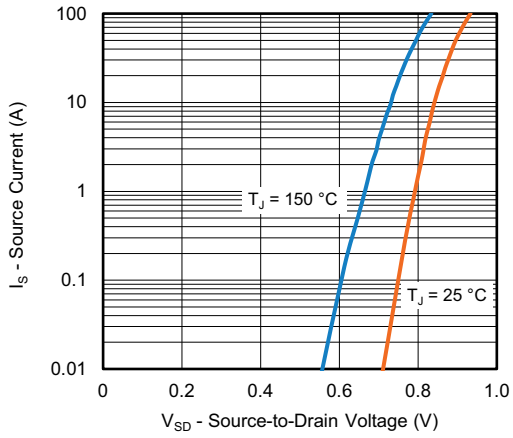
Gate Charge



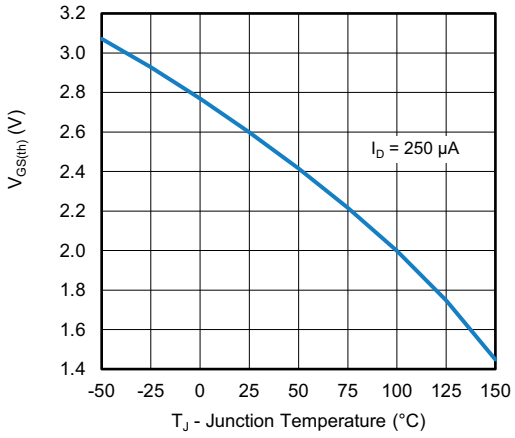
On-Resistance vs. Junction Temperature

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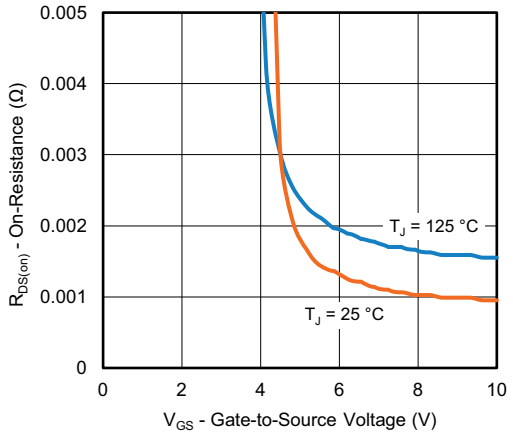
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



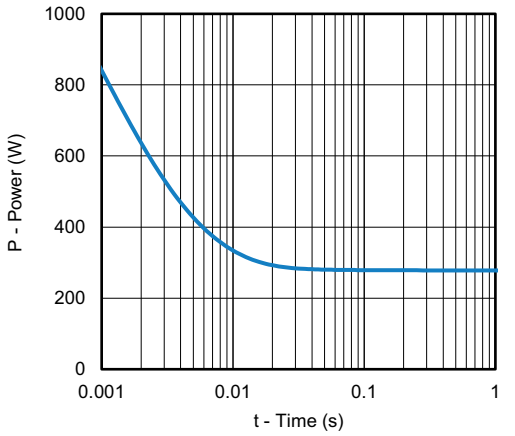
Source-Drain Diode Forward Voltage



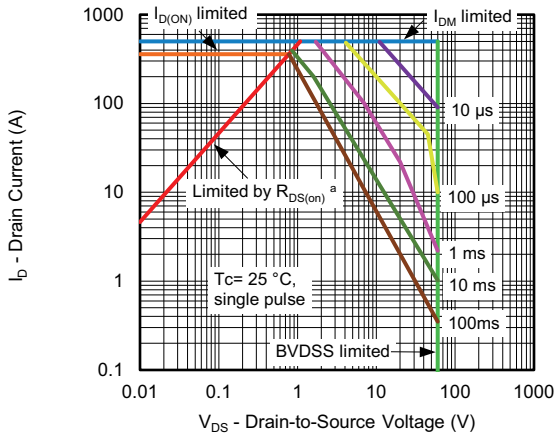
Threshold Voltage



On-Resistance vs. Gate-to-Source Voltage



Single Pulse Power, Junction-to-Case



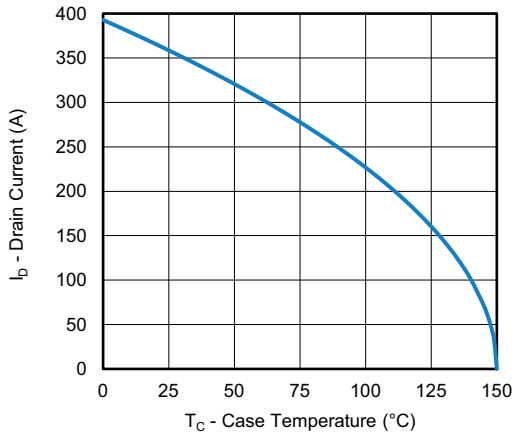
Safe Operating Area, Junction-to-Case

Note

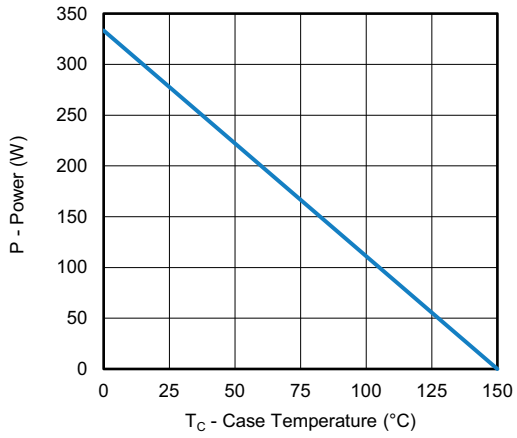
a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

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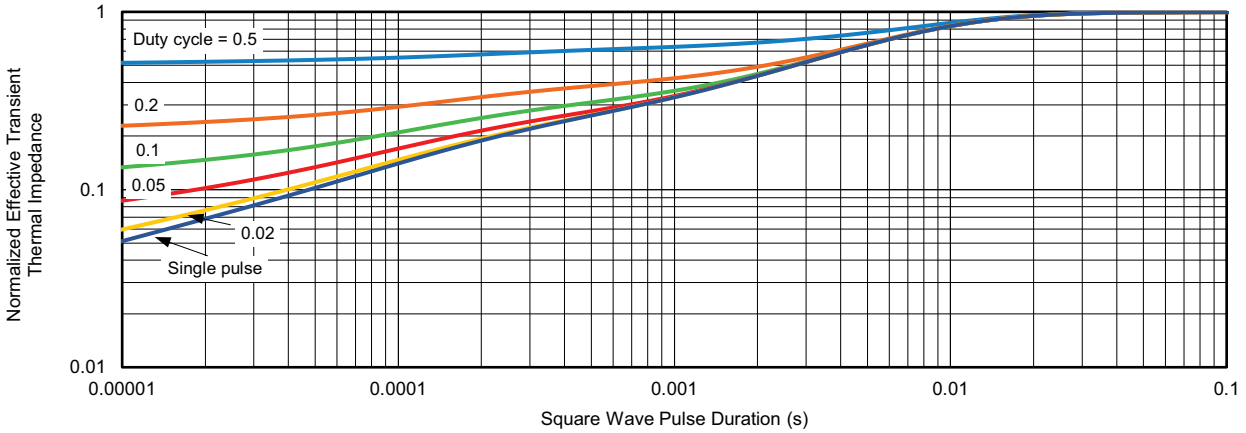
Current Derating [a]



Power, Junction-to-Case

Note

a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit

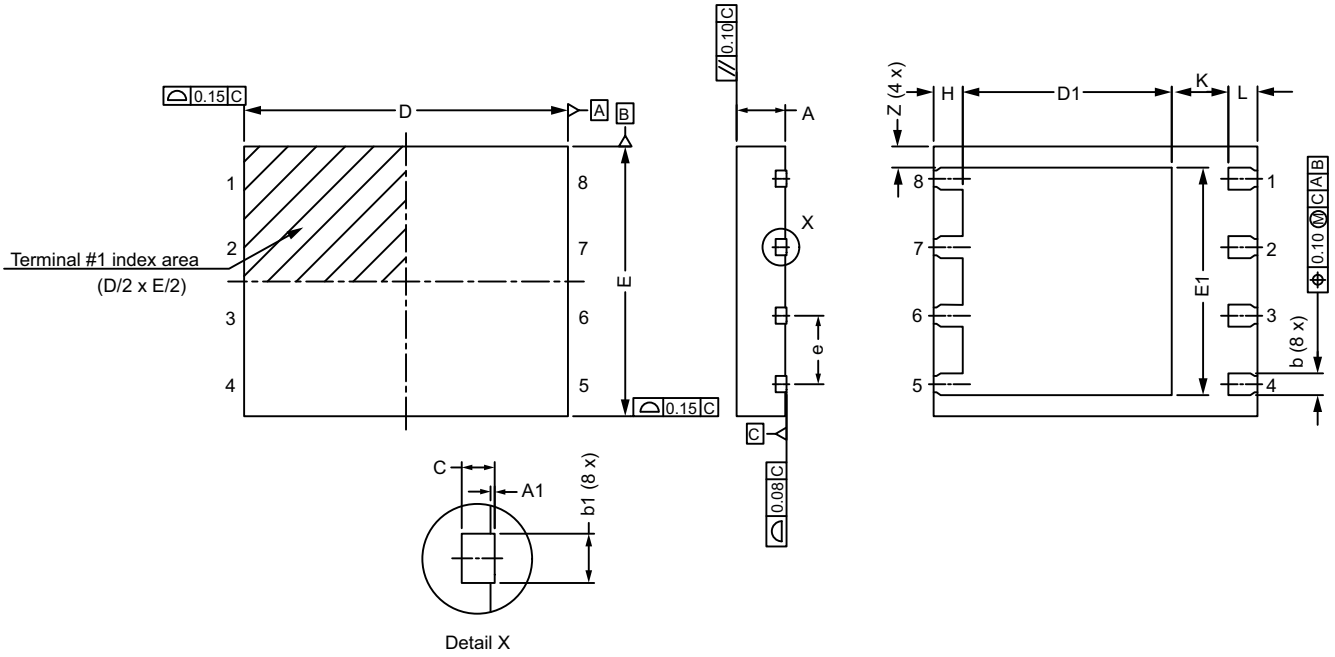


Normalized Thermal Transient Impedance, Junction-to-Case

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PowerPAK® SO-8S BWL

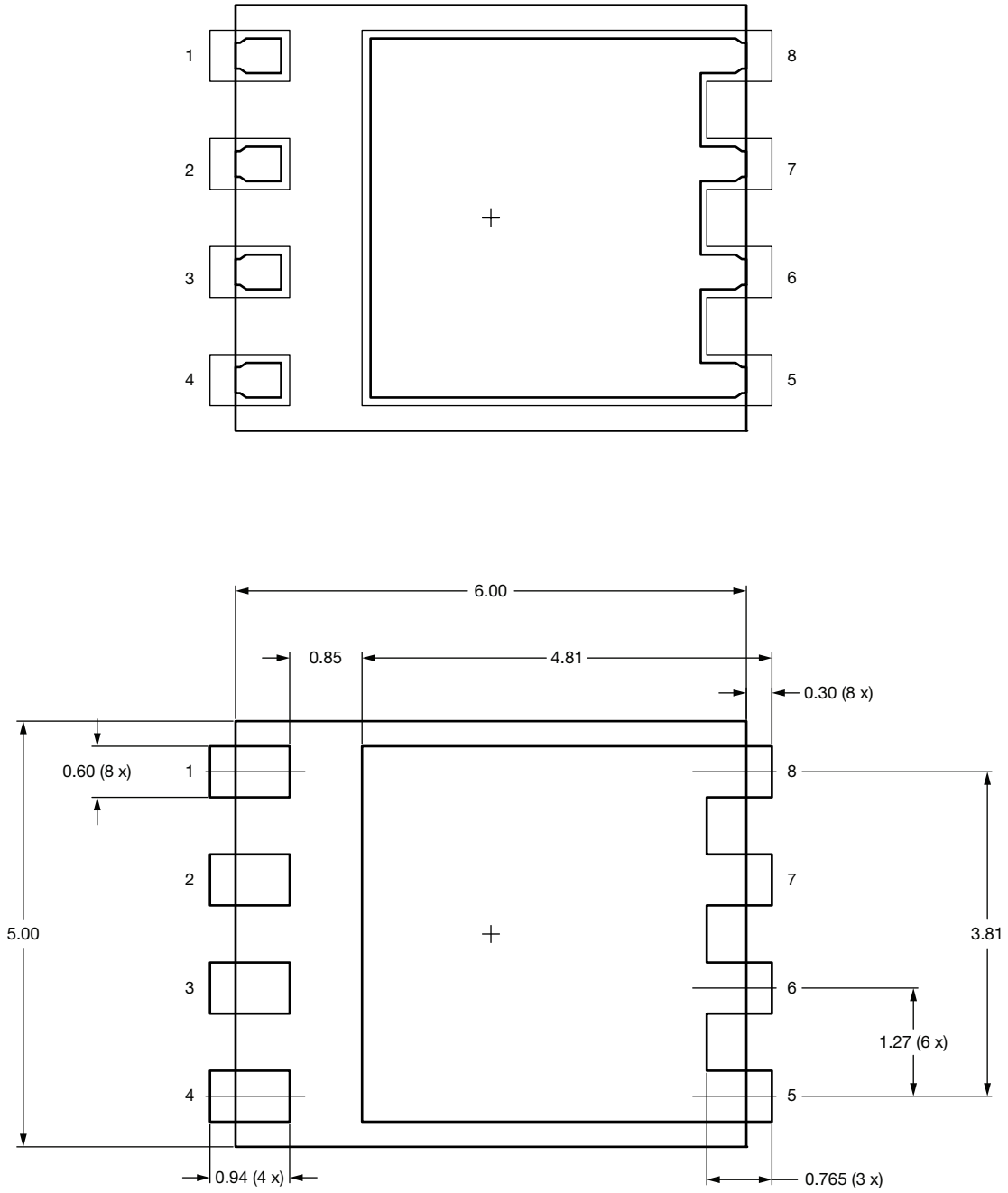


DIM.	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.85	0.90	0.95	0.033	0.035	0.037
A1	-	-	0.05	-	-	0.002
b	0.31	0.41	0.51	0.012	0.016	0.020
b1	0.20	0.30	0.40	0.008	0.012	0.016
c	0.20 ref.			0.008 ref.		
D	5.90	6.00	6.10	0.232	0.236	0.240
D1	3.78	3.88	3.98	0.149	0.153	0.157
E	4.90	5.00	5.10	0.193	0.197	0.201
E1	4.12	4.22	4.32	0.162	0.166	0.170
e	1.27 BSC			0.050 BSC		
H	0.44	0.54	0.64	0.017	0.021	0.025
K	1.05 ref.			0.041 ref.		
L	0.44	0.54	0.64	0.017	0.021	0.025
Z	0.39 ref.			0.015 ref.		
ECN: C20-0936-Rev. A, 03-Aug-2020 DWG: 6082						

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Recommended Land Pattern PowerPAK® SO-8S BWL



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